TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX4051F, TC74LVX4051FT, TC74LVX4051FK TC74LVX4052F, TC74LVX4052FT, TC74LVX4052FK TC74LVX4053F, TC74LVX4053FT, TC74LVX4053FK

TC74LVX4051F/FT/FK

8-Channel Analog Multiplexer/Demultiplexer TC74LVX4052F/FT/FK Dual 4-Channel Analog Multiplexer/Demultiplexer

TC74LVX4053F/FT/FK

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74LVX4051/4052/4053 are high-speed, low-voltage drive analog multiplexer/demultiplexers using silicon gate CMOS technology. In 3 V and 5 V systems these can achieve high-speed operation with the low power dissipation that is a feature of CMOS.

The TC74LVX4051/4052/4053 offer analog/digital signal selection as well as mixed signals. The 4051 has an 8-channel configuration, the 4052 has an 4-channel × 2 configuration, and the 4053 has a 2-channel × 3 configuration.

The switches for each channel are turned ON by the control pin digital signals.

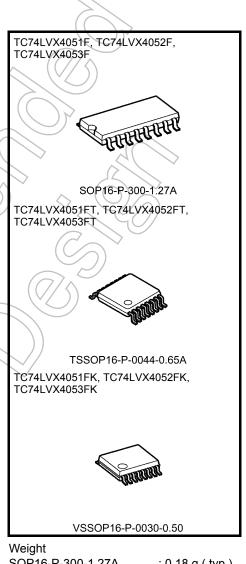
Although the control signal logical amplitude (V_{CC} – GND) is small, the device can perform large-amplitude (V_{CC} – V_{EE}) signal switching.

For example, if $V_{CC} = 3 \text{ V}$, GND = 0 V, and $V_{EE} = -3 \text{ V}$, signals between -3 V and +3 V can be switched from the logical circuit using a single 3 V power supply.

All control input pins are equipped with a newly developed input protection circuit that avoids the need for a diode on the plus side (forward side from the input to the V_{CC}). As a result, for example, 5 V signals can be permitted on the inputs even when the power supply voltage to the circuits is off. As a result of this input power protection, the TC74LVX4051/4052/4053 can be used in a variety of applications, including in the system which has two power supplies, and in battery backup circuits.

Features

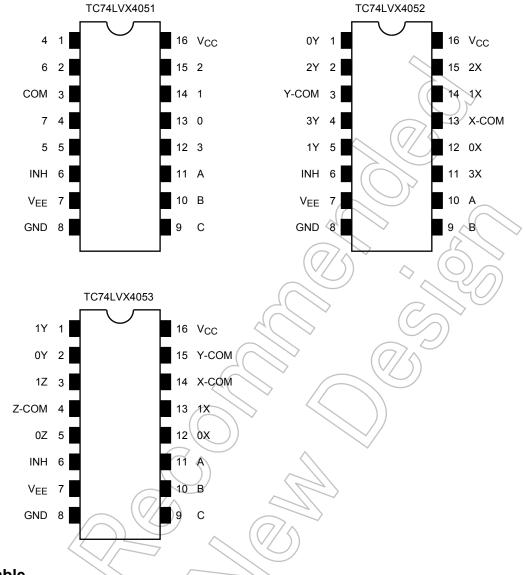
- Low ON resistance: $R_{on} = 22 \Omega$ (typ.) (V_{CC} V_{EE} = 3 V) $R_{on} = 15 \Omega$ (typ.) (V_{CC} - V_{EE} = 6 V)
- High speed: $t_{pd} = 3 \text{ ns} (typ.) (V_{CC} = 3.0 \text{ V})$
- Low power dissipation: $I_{CC} = 4 \mu A (max) (Ta = 25^{\circ}C)$
- Input level: V_{IL} = 0.8 V (max) (V_{CC} = 3 V) V_{IH} = 2.0 V (min) (V_{CC} = 3 V)
- Power down protection is provided on all control inputs
- Pin and function compatible with 74HC4051/4052/4053



	Veight
: 0.18 g (typ	SOP16-P-300-1.27A
65A : 0.06 g (typ	SSOP16-P-0044-0.65A
50 : 0.02 g (typ	/SSOP16-P-0030-0.50
65A : 0.06 g (typ	SSOP16-P-0044-0.65A

Start of commercial production 2000-09

Pin Assignment (top view)



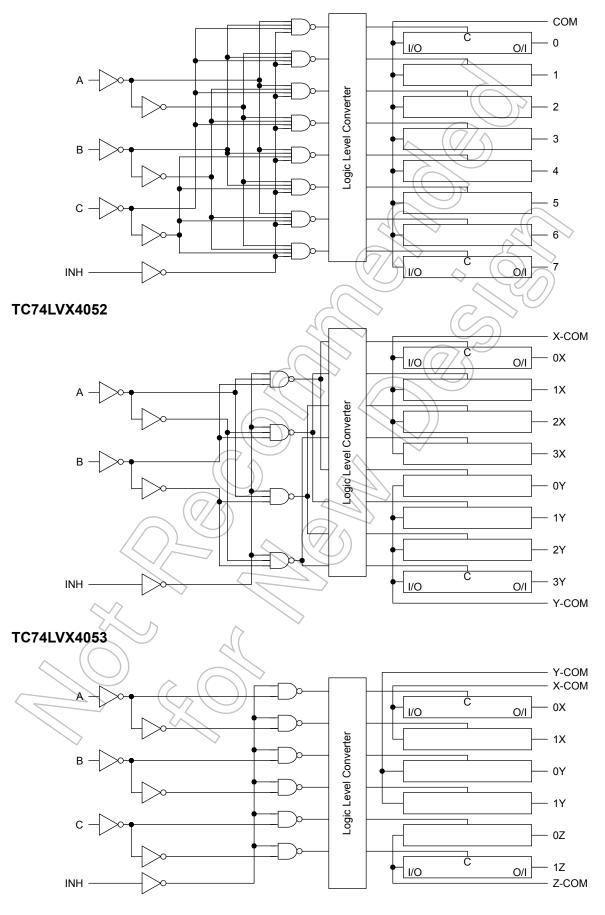
Truth Table

	Control	I Inputs			"ON" Channel	
Inhibit	C*	В	A	TC74LVX4051	TC74LVX4052	TC74LVX4053
L		L V	L	0	0X, 0Y	0X, 0Y, 0Z
			Н	1	1X, 1Y	1X, 0Y, 0Z
)	Н)) L	2	2X, 2Y	0X, 1Y, 0Z
1	L) F	Н	3	3X, 3Y	1X, 1Y, 0Z
L	Н		L	4		0X, 0Y, 1Z
L	Н	L	Н	5		1X, 0Y, 1Z
L	Н	Н	L	6		0X, 1Y, 1Z
L	Н	Н	Н	7		1X, 1Y, 1Z
Н	Х	Х	Х	None	None	None

X: Don't care, *: Except TC74LVX4052

System Diagram

TC74LVX4051



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	–0.5 to 7.0	v	
Fower supply voltage	V_{CC} to V_{EE}	-0.5 to 7.0		
Control input voltage	V _{IN}	-0.5 to 7.0	V	$\langle \rangle$
Switch I/O voltage	V _{I/O}	V_{EE} – 0.5 to V_{CC} + 0.5	V	<u> </u>
Input diode current	I _{IK}	-20	mA	
I/O diode current	I _{IOK}	±20	mA	$\overline{\overline{\overline{n}}}$
Switch through current	lΤ	±25	mA	$\bigvee \bigcirc$
DC V_{CC} or ground current	ICC	±50	mA	\sim
Power dissipation	PD	180	mW	7(
Storage temperature	T _{stg}	-65 to 150	0 °C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
	V _{CC}	2 to 6	
Power supply voltage	VEE	-4 to 0	V
	V _{CC} to V _{EE}	2 to 6	
Input voltage	VIR	0 to 6.0	V
Switch I/O voltage	V _{1/O}	V _{EE} to V _{CC}	V
Operating temperature	T _{opr}	_40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 \pm 0.3 V)	ns/V
Input rise and fait linte	avav	0 to 20 (V _{CC} = 5 \pm 0.5 V)	115/ V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



Electrical Characteristics

DC Electrical Characteristics

Character	Characteristics		istics Symbol Test Condition			٦	Га = 25°С)	Ta = -40	to 85°C	Unit												
Character	151105	Symbol	Test Condition	$V_{EE}(V)$	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit												
					2.0	1.5	_	X	1.5	_													
	High-level	VIH			3.0	2.0	_	À	2.0	_													
	i ligii-level	VН			4.5	3.15	_	Å	3.15	_													
Input voltage					6.0	4.2	-((77~	4.2	—	V												
input voltage					2.0	_<) - (0.5	—	0.5	v												
	Low-level	VIL			3.0	(0.8	—	0.8													
	Low-Icvel	۷IL			4.5		\bigcirc	1.35	—	1.35													
					6.0	\mathcal{A}		1.8	f	1.8													
			$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	Ĥ	200		24	\geq													
			$V_{I/O} = V_{CC}$ to V_{EE}	GND	3.0	2/~	45	86	5	108													
		R_{ON} II/O = 2 mA		GND	4.5		24 <	37	SH	46													
ON resistance			R _{ON}	R _{ON}	R _{ON}	RON	RoN		1//0 2 11// (-3.0	3.0	_	17	26	L FC	33	Ω						
						$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	× —	28	73	<u>~</u>	84	25									
			$V_{I/O} = V_{CC} \text{ or } V_{EE}$	GND	3.0		22	38	—	44													
															$I_{I/O} = 2 \text{ mA}$	GND	4.5	—	(17/	27	—	31	
			40	-3.0	3.0		15	24	—	28													
			$V_{IN} = V_{IL} \text{ or } V_{IH}$	GND	2.0	_	10	25		35													
Difference of ON resistance between	ce between $\Delta R_{ON} V_{I/C}$		$V_{I/O} = V_{CC}$ to V_{EE}	GND	3.0	\searrow	5	15	—	20	Ω												
switches		$I_{I/O} = 2 \text{ mA}$	GND	4.5	_	5	13	—	18														
				-3.0	3.0	_	5	10	—	15													
Input/Output lea	kage		$V_{OS} = V_{CC}$ or GND	GND	3.0	<u> </u>	—	±0.25	—	±2.5													
current (switch OFF)		IOFF	V _{IS} = GND to V _{CC} V _{IN} = V _{IL} or V _{IH}	-3.0	3.0	_	—	±0.5	—	±5.0	μA												
Input/Output lea	ikage		$V_{OS} = V_{CC} \text{ or } GND$	GND	3.0	_	_	±0.25	_	±2.5	•												
current (switch ON, out	out open)	Vin	$V_{IN} = V_{IL} \text{ or } V_{IH}$	-3.0	3.0			±0.5	_	±5.0	μA												
Control input cu	rrent	IIN	$V_{IN} = V_{CC} \text{ or } GND$	GND	6.0	_		±0.1	_	±0.1	μA												
Quippont auro		N-	Mar Nor of CND	GND	3.0	_	—	4.0	_	40.0	^												
Quiescent supp	ly current	lcc	$V_{IN} = V_{CC}$ or GND	-3.0	3.0	—	—	8.0	—	80.0	μA												

AC Electrical Characteristics ($C_L = 50 \text{ pF}$, Input: $t_r = t_f = 3 \text{ ns}$, GND = 0 V)

Characteristics	Currente e l	Та	at Canadition			7	Га = 25°С)	Ta = -40	to 85°C	Unit											
Characteristics Symbol		Test Condition		$V_{\text{EE}}(V)$	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit											
Phase difference between				GND	2.0	—	3.2	6.0	—	6.9												
	φl/O	Alltime		GND	3.0		1.8	3.0		3.5	ns											
input and output	φι/Ο	All type	:5	GND	4.5	_	1.3	1.8		2.1	115											
				-3.0	3.0	_	1.1	1.3	\leq	1.5												
				GND	2.0	_	9.0	TT.	2_	20												
Output enable time	t _{pZL}	Figure	1 (Note 1)	GND	3.0	\leq	5.7	9.0	_	11	ns											
	t _{pZH}	rigure		GND	4.5		4.5	6.0		7.0	115											
				-3.0	3.0	_((5.8	8.0		10												
				GND	2.0		13.5	21		25												
Output disable time	t _{pLZ}	Figure	1 (Note 1)	GND	3.0 🗸	1(11.3	15	AF	18	ns											
	tpHZ		rigure	ligure i (inote i)	GND	4.5	\mathbb{R}	10.3	12	\geq	14	115										
																	-3.0	3.0	$\langle \gamma \rangle$	10.9	13	
Control input capacitance	C _{in}	All type	es (Note 2)	— (\sim	2	5	(10)	C4)/	10	pF											
		4051		G	\bigcirc		11	25		25												
COMMON terminal capacitance	CIS	C _{IS}	C _{IS}	C _{IS}	C _{IS}	C _{IS}	C _{IS}	C _{IS}	4052	Figure 2 (Note 2)	-3.0	3.0	—	9(20	—	20	pF				
		4053	. ,		$\langle \rangle$		$\overline{\overline{z}}$	15		15												
		4051	- C	$\left(\right)$			6) 13		13												
SWITCH terminal capacitance	C _{OS}	4052	Figure 2 (Note 2)	-3.0	3.0	\sim	6	13	—	13	pF											
		4053		$\langle \rangle$))6	13		13												
		4051					3	6		6												
Feedthrough capacitance	C _{IOS} 4052 Fig	4052 Figure 2 (Note 2)	C _{IOS} 4052 Figure	Figure 2 (Note 2)	-3.0	3.0	_~	3	6		6	pF										
		4053					3	6		6												
		4051		\sim		\geq	14															
Power dissipation capacitance	CPD	CPD 4052 Figure 2		GND	6.0	—	24	—	—	—	pF											
		4053			$\left(\right)$		18															

Note 1: $R_L = 1 k\Omega$

Note 2: Cin, CIS, COS and CIOS are guaranteed by the design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

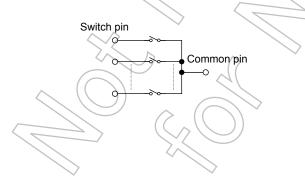
Average operating current can be obtained by the equation:

ICC (opr) = CPD · VCC · fIN + ICC

Analog Switch Characteristics (GND = 0 V, $Ta = 25^{\circ}C$) (Note)

Characteristics	Symbol	Test Condition					Test Condition			Тур.	Unit
Characteristics	Symbol	Test Condition		V _{EE} (V)	$V_{CC}(V)$	тур.	Unit				
			$V_{IN} = 2.0 V_{p-p}$	0	3.0	0.100					
Sine Wave Distortion (T.H.D)		R _L = 10 kΩ, C _L = 50 pF, f _{IN} = 1 kHz	$V_{IN} = 4.0 \ V_{p\text{-}p}$	Q	4.5	0.030	%				
		$V_{IN}=6.0 \ V_{p\text{-}p}$	-0.3	3.0	0.020						
			4051		\sum	150					
			4052	0	3.0	180					
		Adjust f_{IN} voltage to obtain 0dBm at V_{OS} .	4053	$(// \uparrow$		200					
_		Increase f _{IN} frequency until dB	4051			150					
Frequency response (switch ON)	f _{max}	meter reads –3dB.	4052	0	4.5	180	MHz				
		$R_L = 50 \Omega$, $C_L = 10 pF$, $f_{IN} = 1 MHz$, sine wave	4053	ک		200					
	Figure 3	Figure 3	4051		$\mathcal{A}($	150					
			4052	-3.0	3.0	180					
		(4053	\Diamond	(O)	200					
		V_{IN} is centered at $(V_{CC} - V_{EE})/2$.	0	3.0	/_45						
		Adjust input for 0dBm. $R_L = 600 \Omega$, $C_L = 50 pF$, $f_{IN} = 1 MI$	0	4.5	-45						
Feed through attenuation (switch OFF)	_	Figure 4	, ,	-3.0	3.0	-45	dB				
(Switch OFF)			(0	3.0	-60					
		$R_L = 50 \ \Omega$, $C_L = 10 \ pF$, $f_{IN} = 1 \ MH$	0	0 4.5	-60						
			-3.0	3.0	-60						
Crosstalk		R_L = 600 Ω,C_L = 50 pF, f _{IN} = 1 MI	Hz, square wave	0	3.0	90					
(control input to signal output)	—	$(t_r = t_f = 6 \text{ ns})$		0	4.5	150	mV				
		Figure 5		-3.0	3.0	120					
Oracastalla		Adjust V _{IN} to obtain 0dBm at input		0	3.0	-45					
Crosstalk (between any switches)		$R_L = 600 \ \Omega$, $C_L = 50 \ pF$, $f_{IN} = 1 \ MI$	0	4.5	-45	dB					
	\bigcirc)`	Figure 6		-3.0	3.0	-45					

Note: These characteristics are determined by design of devices.



AC Test Circuit

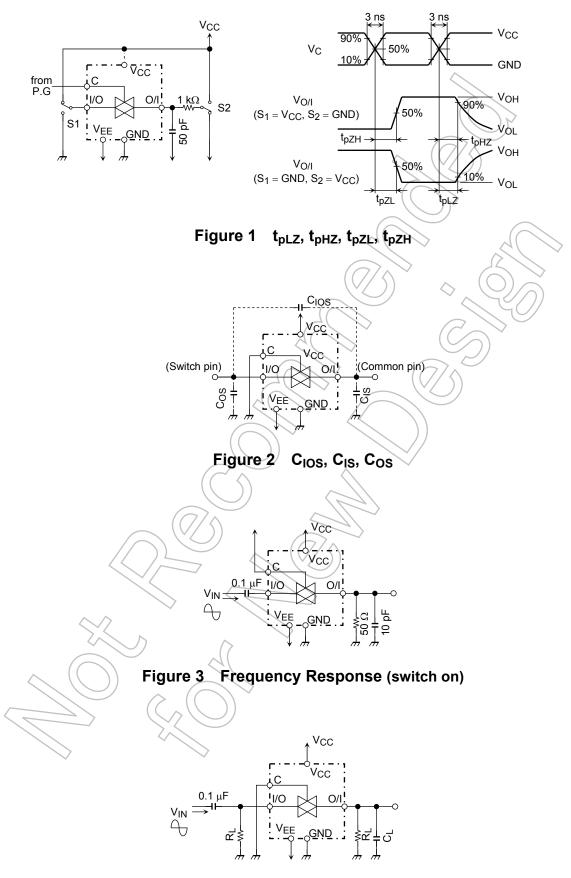
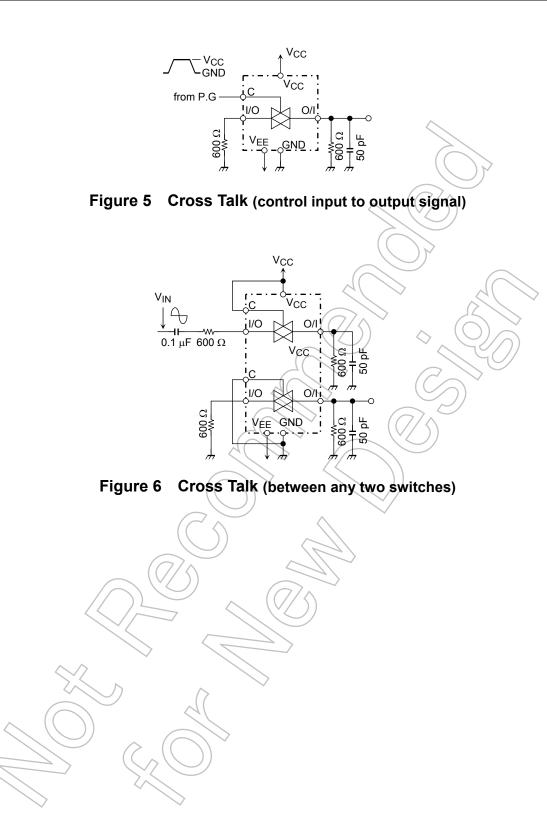


Figure 4 Feedthrough

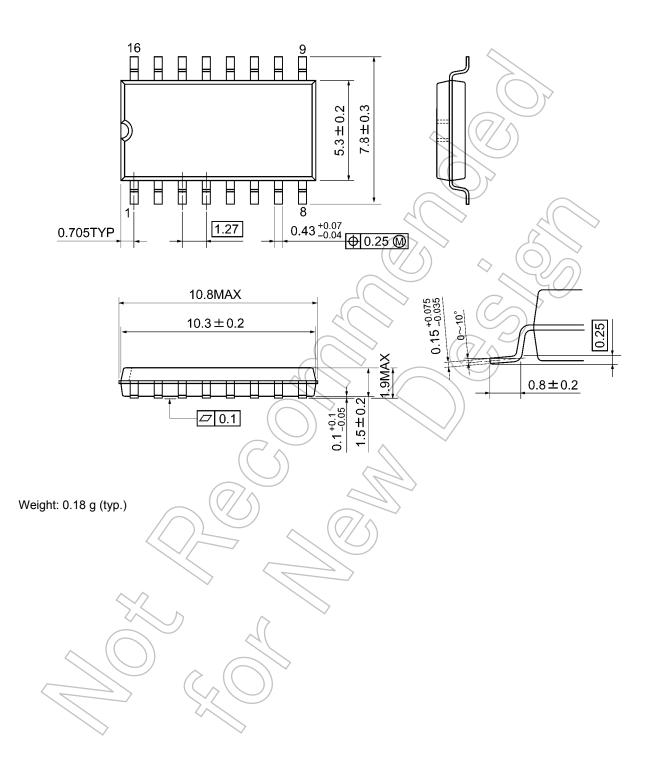




Package Dimensions

SOP16-P-300-1.27A

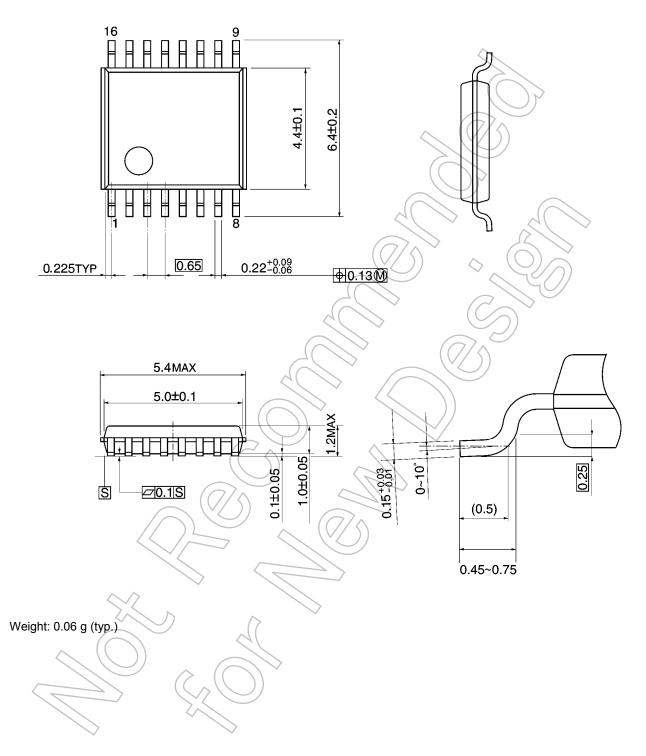
Unit: mm



Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm

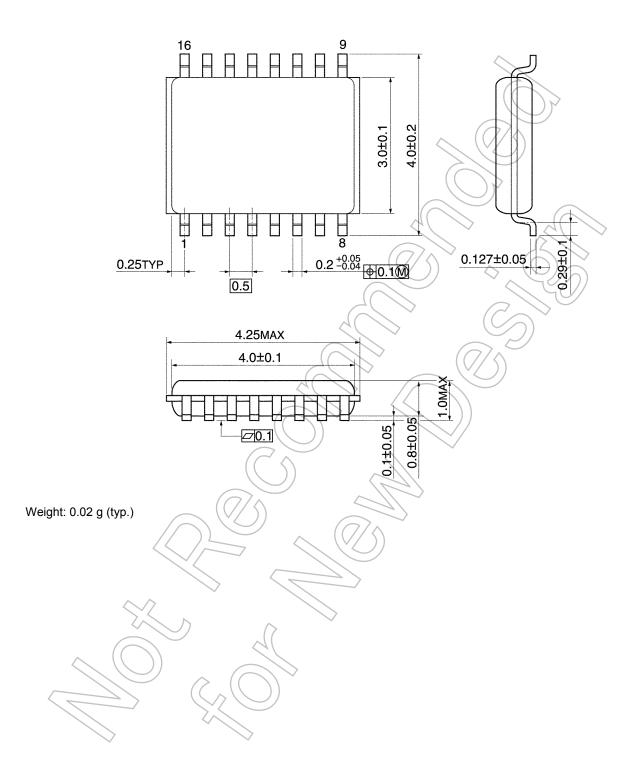


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Package Dimensions

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Unit: mm



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